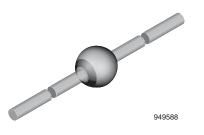
www.vishay.com

1N5624, 1N5625, 1N5626, 1N5627

Vishay Semiconductors

Standard Avalanche Sinterglass Diode



MECHANICAL DATA

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

Mounting position: any

Weight: approx. 858 mg

FEATURES

- Glass passivated junction
- Hermetically sealed package
- · Controlled avalanche characteristics
- Low reverse current
- High surge current loading
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

• Rectification diode, general purpose

ORDERING INFORMATION (Example)					
DEVICE NAME	ORDERING CODE	TAPED UNITS	MINIMUM ORDER QUANTITY		
1N5627	1N5627-TR	2500 per 10" tape and reel	12 500		
1N5627	1N5627-TAP	2500 per ammopack	12 500		

PARTS TABLE		
PART	TYPE DIFFERENTIATION	PACKAGE
1N5624	$V_{R} = 200 \text{ V}; \text{ I}_{F(AV)} = 3 \text{ A}$	SOD-64
1N5625	V _R = 400 V; I _{F(AV)} = 3 A	SOD-64
1N5626	V _R = 600 V; I _{F(AV)} = 3 A	SOD-64
1N5627	V _R = 800 V; I _{F(AV)} = 3 A	SOD-64

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT		
		1N5624	$V_{R} = V_{RRM}$	200	V		
Reverse voltage = repetitive peak reverse	See electrical characteristics	1N5625	$V_{R} = V_{RRM}$	400	V		
voltage		1N5626	$V_{R} = V_{RRM}$	600	V		
		1N5627	$V_{R} = V_{RRM}$	800	V		
Peak forward surge current	t _p = 10 ms, half sinewave		I _{FSM}	100	А		
Repetitive peak forward current			I _{FRM}	18	А		
Average forward current			I _{F(AV)}	3	А		
Pulse avalanche peak power	t _p = 20 μs, half sine wave, T _j = 175 °C		P _R	1000	W		
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	$I_{(BR)R}$ = 1 A, T_j = 175 °C		E _R	20	mJ		
i ² *t-rating			i ² *t	40	A²∗s		
Junction and storage temperature range			$T_j = T_{stg}$	- 55 to + 175	°C		

MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION SYMBOL VALUE		UNIT		
Junction ambient	$I = 10 \text{ mm}, T_L = \text{constant}$	R _{thJA}	25	K/W	
	On PC board with spacing 25 mm	R _{thJA}	70	K/W	

Rev. 1.5, 03-Sep-12

1

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 3 A		V _F	-	-	1	V
Reverse current	$V_{R} = V_{RRM}$		I _R	-	0.1	1	μA
neverse current	$V_R = V_{RRM}, T_j = 100 \ ^\circ C$		I _R	-	5	10	μA
Breakdown voltage	$I_R = 100 \ \mu A, \ t_p/T = 0.01, \ t_p = 0.3 \ ms$		V _(BR)	-	-	1600	V
Diode capacitance	V _R = 4 V, f = 1 MHz		CD	-	40	60	pF
Reverse recovery time	I _F = 0.5 A, I _R = 1 A, i _R = 0.25 A		t _{rr}	-	3.5	5	μs
neverse recovery time	$I_F = 1 \text{ A}, \text{ dI/d}_t = 5 \text{ A/}\mu\text{s}, \text{ V}_R = 50 \text{ V}$		t _{rr}	-	4.5	7.5	μs
Reverse recovery charge	$I_F = 1 \text{ A}, \text{ dI/d}_t = 5 \text{ A/}\mu\text{s}$		Q _{rr}	-	8	12	μC

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

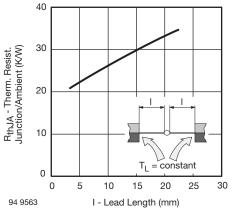


Fig. 1 - Max. Thermal Resistance vs. Lead Length

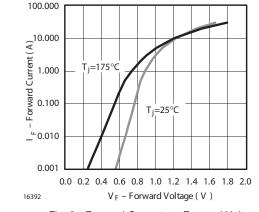


Fig. 2 - Forward Current vs. Forward Voltage

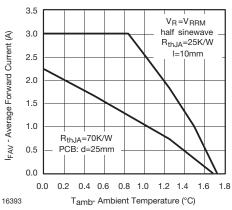


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

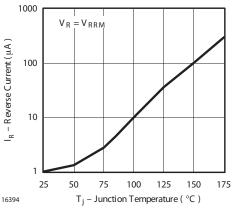


Fig. 4 - Reverse Current vs. Junction Temperature

Rev. 1.5, 03-Sep-12

2

Document Number: 86063

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



1N5624, 1N5625, 1N5626, 1N5627

Vishay Semiconductors

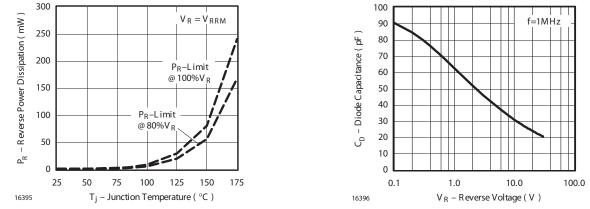
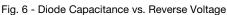
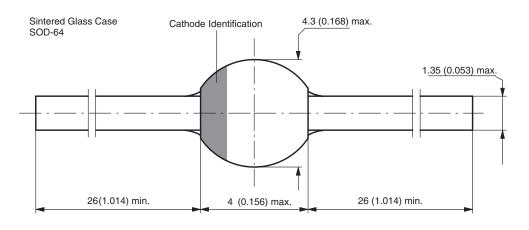


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature



PACKAGE DIMENSIONS in millimeters (inches): SOD-64



Document-No.: 6.563-5006.4-4 Rev. 3 - Date: 09.February.2005 94 9587



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.